

SANYO Semiconductors DATA SHEET

SB01W05C

Schottky Barrier Diode (Twin Type • Cathode Common)

50V, 100mA Rectifier

Applications

• High frequency rectification (switching regulators, converters, choppers).

Features

- Low forward voltage (VF max=0.55V).
- Fast reverse recorvery time (t_{rr} max=10ns).
- · Low switching noise.
- · Low leakage current and high reliability due to highly reliable planar structure.

Specifications

Absolute Maximum Ratings at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		50	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		55	V
Average Output Current	IO		100	mA
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	2	А
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Reverse Voltage	VR	I _R =50μA	50			V
Forward Voltage	VF	I _F =100mA			0.55	V
Reverse Current	IR	V _R =25V			15	μΑ
Interterminal Capacitance	С	V _R =10V, f=1MHz		4.4		pF

Marking: M Continued on next page.

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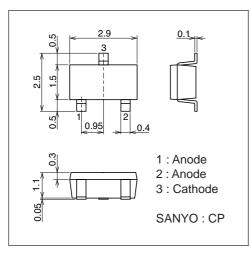
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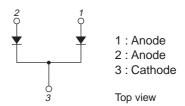
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Reverse Recovery Time	trr	IF=IR=10mA, See specified Test Circuit.			10	ns
Thermal Resistance	Rth(j-a)1			560		°C/W
	Rth(j-a)2	Mounted on Cu-foild area of 16mm ² ×0.2mm		410		°C/W
		on glass epoxy board				

Package Dimensions

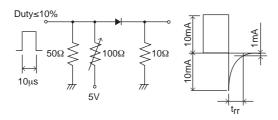
unit : mm (typ) 7013A-006

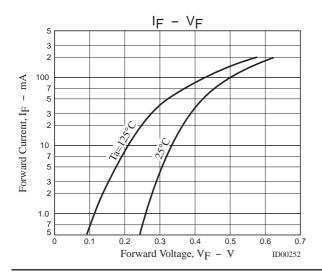


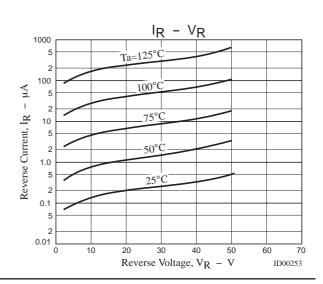
Electrical Connection



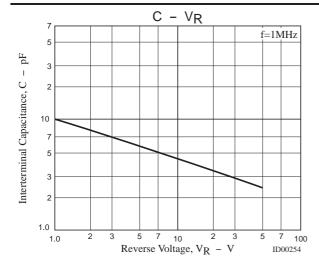
trr Test Circuit

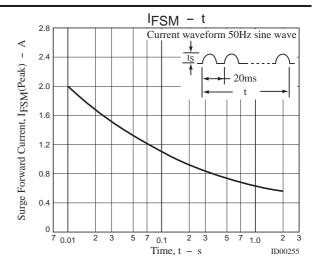






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